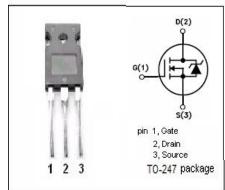


# isc N-Channel MOSFET Transistor

# IRFP32N50K

### • FEATURES

- · With TO-247 packaging
- With low gate drive requirements
- · Easy to drive
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### APPLICATIONS

· Switching applications



### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	500	V	
$V_{GSS}$	Gate-Source Voltage	±30	V	
Ι <sub>D</sub>	Drain Current-Continuous@Tc=25℃ Tc=100℃	32 20	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	130	А	
P <sub>D</sub>	Total Dissipation	460	W	
Tj	Operating Junction Temperature	-55~150	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature	-55~150	${\mathbb C}$	

	mm		
DIM	MIN	MAX	
Α	19.80	20.20	
В	15.40	15.80	
C	4.90	5.10	
D	0.90	1.10	
E	1.40	1.60	
F	1.90	2.10	
G	10.80	11.00	
Н	2.40	2.60	
J	0.50	0.70	
K	19.50	20.50	
Р	3.90	4.10	
Q	3.30	3.50	
U	5.20	5.40	
V	2.90	3.10	

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.26	°C/W

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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	500			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	3.0		5.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =32A		135	160	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0V;@Tc=25°C V <sub>DS</sub> = 400V; V <sub>GS</sub> = 0V;Tc=150°C			50 250	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =32A, V <sub>GS</sub> = 0 V			1.5	V

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